

Description

The LM9926 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 20V$ $I_D = 6.5A$

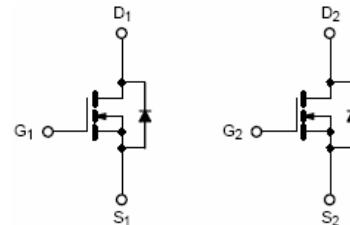
$R_{DS(ON)} < 28m\Omega$ @ $V_{GS}=10V$ (Type: $20m\Omega$)

Application

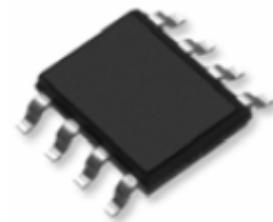
Battery protection

Load switch

Wireless charging



Schematic diagram



SOP-8 top view

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
LM9926	SOP-8	9926	3000

Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)

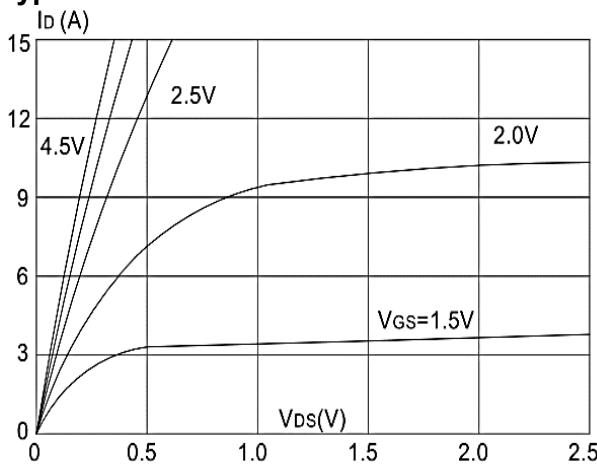
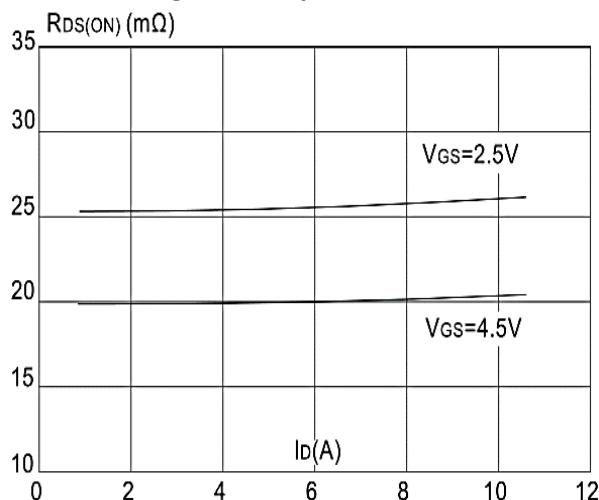
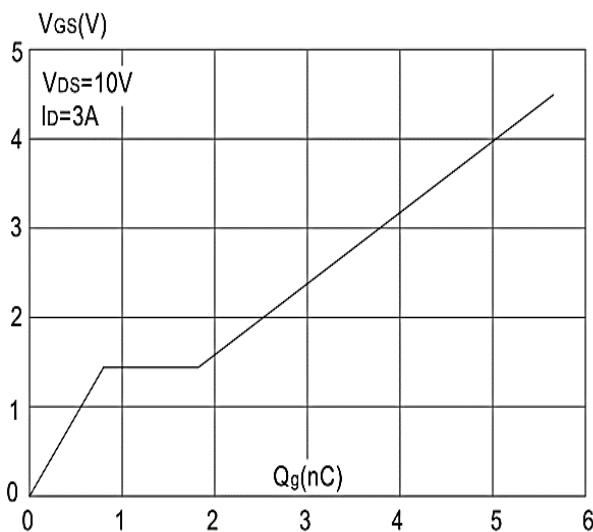
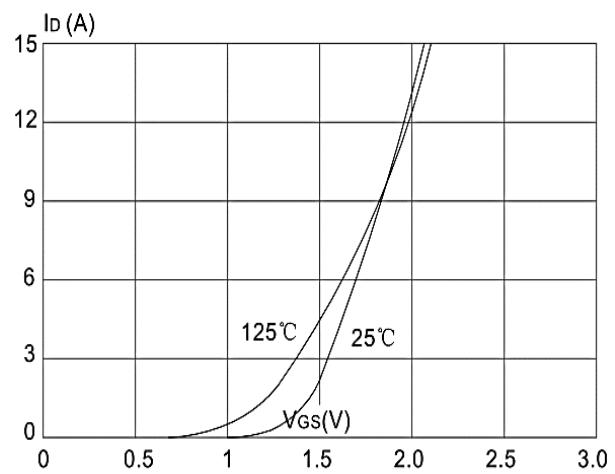
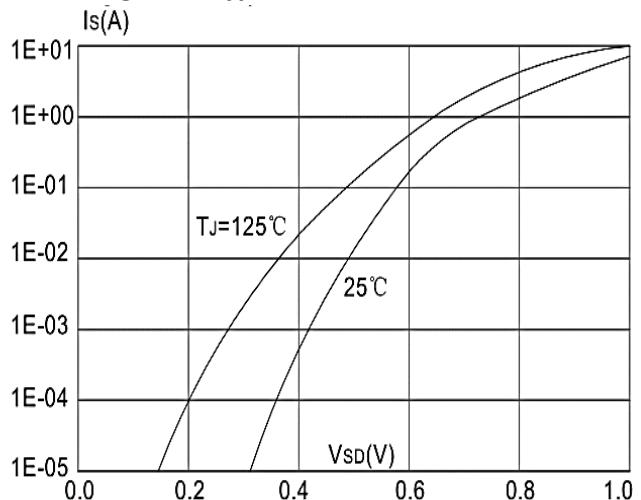
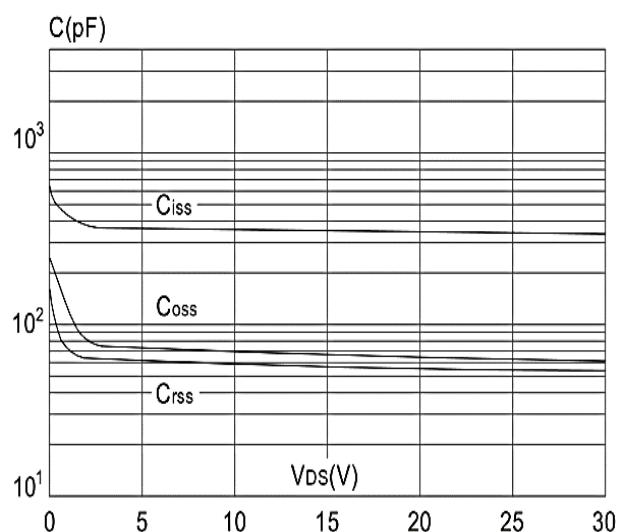
Symbol	Parameter	Rating	Units
V _{DS}	Drain-Source Voltage	20	V
V _{GS}	Gate-Source Voltage	± 12	V
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	6.5	A
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	4	A
I _{DM}	Pulsed Drain Current ²	24	A
P _D @T _A =25°C	Total Power Dissipation ⁴	1.2	W
T _{TSG}	Storage Temperature Range	-55 to 150	°C
R _{θJA}	Thermal Resistance Junction-Ambient ¹	78	°C/W

Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V(BR)DSS	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	20	22	-	V
IDSS	Zero Gate Voltage Drain Current	$V_{DS}=20\text{V}, V_{GS}=0\text{V},$	-	-	1.0	μA
IGSS	Gate to Body Leakage Current	$V_{DS}=0\text{V}, V_{GS}=\pm 12\text{V}$	-	-	± 100	nA
VGS(th)	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.5	0.7	1.2	V
RDS(on)	Static Drain-Source on-Resistance note3	$V_{GS}=4.5\text{V}, I_D=6\text{A}$	-	20	28	$\text{m}\Omega$
		$V_{GS}=2.5\text{V}, I_D=5\text{A}$	-	25.5	38	
Ciss	Input Capacitance	$V_{DS}=10\text{V}, V_{GS}=0\text{V}, f=1.0\text{MHz}$	-	358	-	pF
Coss	Output Capacitance		-	69.3	-	pF
Crss	Reverse Transfer Capacitance		-	58.5	-	pF
Qg	Total Gate Charge	$V_{DS}=10\text{V}, I_D=3\text{A}, V_{GS}=4.5\text{V}$	-	5.6	-	nC
Qgs	Gate-Source Charge		-	0.8	-	nC
Qgd	Gate-Drain("Miller") Charge		-	1.0	-	nC
td(on)	Turn-on Delay Time	$V_{DS}=10\text{V}, I_D=6\text{A}, R_G=3\Omega, V_{GS}=4.5\text{V}$	-	16	-	ns
t _r	Turn-on Rise Time		-	51	-	ns
td(off)	Turn-off Delay Time		-	21	-	ns
t _f	Turn-off Fall Time		-	18	-	ns
IS	Maximum Continuous Drain to Source Diode Forward Current		-	-	6	A
ISM	Maximum Pulsed Drain to Source Diode Forward Current		-	-	24	A
VSD	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}, I_S=20\text{A}$	-	-	1.2	V

Notes:

- 1、 Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
- 2、 EAS condition : $T_J = 25^\circ\text{C}$, $V_{DD} = 30\text{V}$, $V_G = 10\text{V}$, $L = 0.5\text{mH}$, $R_G = 25\Omega$, $I_{AS} = 3.5\text{A}$
- 3、 Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 0.5\%$

Typical Characteristics

Figure 1: Output Characteristics

Figure 3: On-resistance vs. Drain Current

Figure 5: Gate Charge Characteristics

Figure 2: Typical Transfer Characteristics

Figure 4: Body Diode Characteristics

Figure 6: Capacitance Characteristics

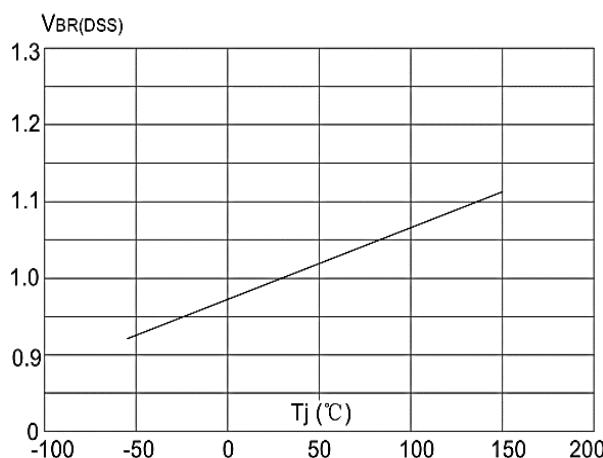


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

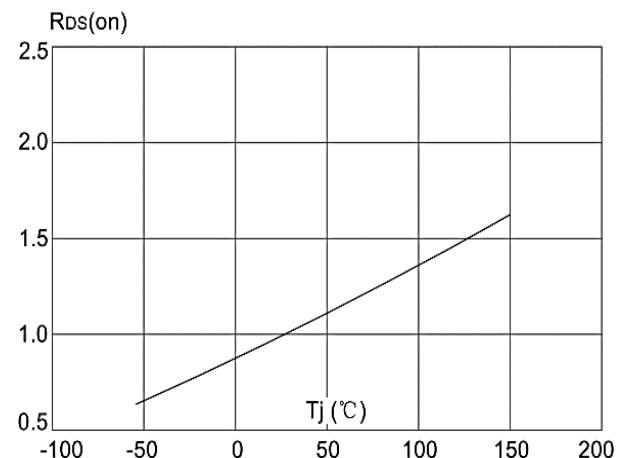


Figure 8: Normalized on Resistance vs. Junction Temperature

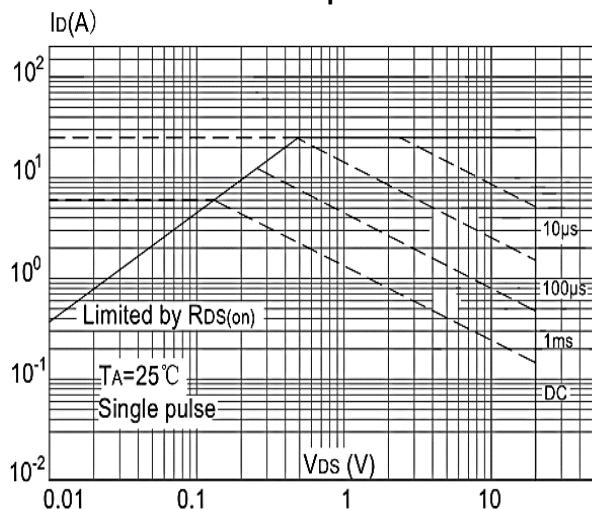


Figure 9: Maximum Safe Operating Area vs. Case Temperature

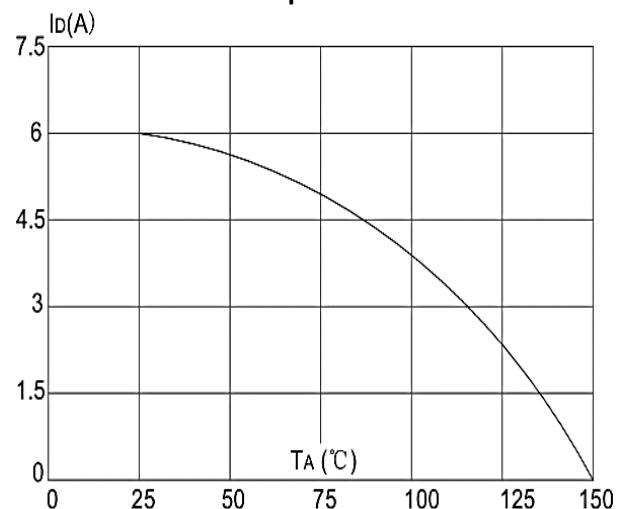


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

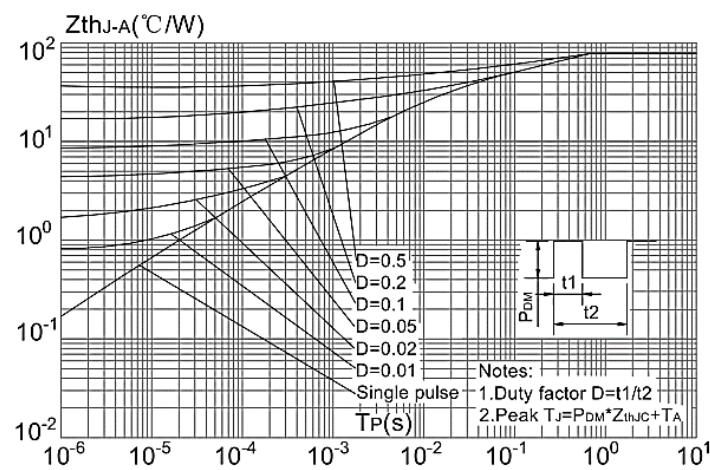
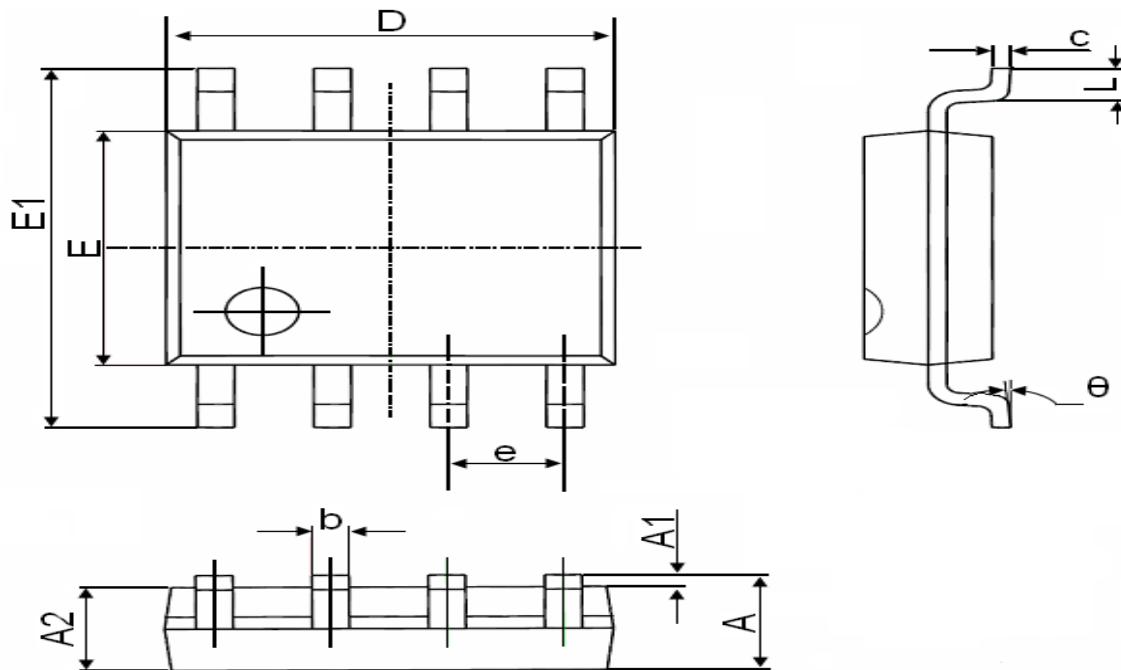


Figure 11: Maximum Effective Transient Thermal Impedance, Junction-to-Case

SOP-8 Package Information


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°		8°	

Shanghai Leiditech Electronic Co.,Ltd
 Email: sale1@leiditech.com
 Tel : +86- 021 50828806
 Fax : +86- 021 50477059